

T493D686K016BT6330

T493 HRA, Tantalum, MnO₂ Tantalum, HRA, 68 uF, 10%, 16 VDC, SMD, MnO₂, Molded, DLA Drawing, B (0.1%/1000 Hrs), 150 mOhms, 7343, 3.1 mm, 1.3 mm



Click [here](#) for the 3D model.

General Information

Series	T493 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, DLA Drawing
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	412.33 mg

Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Specifications

Capacitance	68 uF
Tolerance	10%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	0.15 Ohms (100kHz 25C)
Ripple Current	1000 mA (rms, 100kHz 25C)
Leakage Current	10.9 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.